

# PUMX1

# 40 V, 100 mA NPN/NPN general-purpose transistor Rev. 04 — 20 January 2010 Produ

Product data sheet

#### 1. **Product profile**

### 1.1 General description

NPN/NPN general-purpose transistor with two independently operating transistors in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview** 

Type number Package			PNP/PNP	NPN/PNP
	Nexperia	JEITA	complement	complement
PUMX1	SOT363	SC-88	PUMT1	PUMZ1

### 1.2 Features

- Double general-purpose transistor
- Board-space reduction
- Very small SMD plastic package

### 1.3 Applications

General-purpose switching and amplification

#### **Pinning information** 2.

Dinning Table 2

Table 2.	Filling		
Pin	Description	Simplified outline	Graphic symbol
1	emitter TR1		
2	base TR1	6 5 4	6 5 4
3	collector TR2		TR2
4	emitter TR2	0	(TR1)
5	base TR2	□1 □2 □3	
6	collector TR1		1 2 3
			sym020



### 40 V, 100 mA NPN general-purpose double transistor

### 3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
PUMX1	SC-88	plastic surface-mounted package; 6 leads	SOT363	

### 4. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMX1	Z*Z

<sup>[1] \* = -:</sup> made in Hong Kong

### 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	40	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	100	mA
I <sub>CM</sub>	peak collector current		-	200	mA
I <sub>BM</sub>	peak base current		-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$	-	200	mW
Per device	)				
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$	<u>[1]</u> _	300	mW
T <sub>j</sub>	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

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### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	416	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 7. Characteristics

Table 7. Characteristics

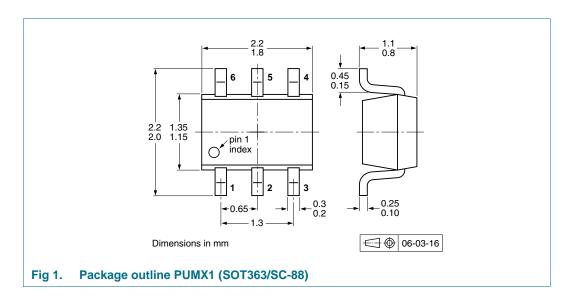
 $T_{amb} = 25$  °C unless otherwise specified.

Parameter	Conditions	Min	<b>T</b>		
	Conditions	IVIIII	Тур	Max	Unit
stor					
collector-base cut-off current	$V_{CB} = 30 \text{ V};$ $I_E = 0 \text{ A}$	-	-	100	nA
	$V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	10	μА
emitter-base cut-off current	$V_{EB} = 4 V;$ $I_C = 0 A$	-	-	100	nA
DC current gain	$V_{CE} = 6 \text{ V};$ $I_C = 1 \text{ mA}$	120	-	-	
collector-emitter saturation voltage	$I_C = 50 \text{ mA};$ $I_B = 5 \text{ mA}$	[1] -	-	200	mV
transition frequency	$I_C = 2 \text{ mA};$ $V_{CE} = 12 \text{ V};$ f = 100  MHz	100	-	-	MHz
collector capacitance	$V_{CB} = 12 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 1 \text{ MHz}$	-	-	1.5	pF
	emitter-base cut-off current  DC current gain  collector-emitter saturation voltage transition frequency		$ \begin{array}{c} \text{collector-base cut-off current} & V_{CB} = 30 \text{ V}; \\ I_E = 0 \text{ A} \\ \hline \\ V_{CB} = 30 \text{ V}; \\ I_E = 0 \text{ A}; \\ \hline \\ T_j = 150 \text{ °C} \\ \hline \\ \text{emitter-base cut-off current} & V_{EB} = 4 \text{ V}; \\ I_C = 0 \text{ A} \\ \hline \\ \text{DC current gain} & V_{CE} = 6 \text{ V}; \\ I_C = 1 \text{ mA} \\ \hline \\ \text{collector-emitter saturation} & I_C = 50 \text{ mA}; \\ V_{B} = 5 \text{ mA} \\ \hline \\ \text{transition frequency} & I_C = 2 \text{ mA}; \\ V_{CE} = 12 \text{ V}; \\ I_C = 100 \text{ MHz} \\ \hline \\ \text{collector capacitance} & V_{CB} = 12 \text{ V}; \\ I_E = I_e = 0 \text{ A}; \\ \hline \end{array} $	$ \begin{array}{c} \text{collector-base cut-off current} \\ & \begin{array}{c} V_{CB} = 30 \text{ V}; \\ I_E = 0 \text{ A} \\ \end{array} \\ & \begin{array}{c} V_{CB} = 30 \text{ V}; \\ I_E = 0 \text{ A}; \\ \end{array} \\ & \begin{array}{c} - \\ \end{array} \\ & \begin{array}{c} - \\ \end{array} \\ \end{array} \\ \text{emitter-base cut-off current} \\ & \begin{array}{c} V_{EB} = 4 \text{ V}; \\ I_C = 0 \text{ A} \\ \end{array} \\ \begin{array}{c} - \\ $	

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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### 8. Package outline



### 9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type Package		Description		Packing quantity	
number				3000	10000
PUMX1 SOT363		4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

<sup>[1]</sup> For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping

### 40 V, 100 mA NPN general-purpose double transistor

### 10. Revision history

### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PUMX1_4	20100120	Product data sheet	-	PUMX1_3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new ide guidelines of NXP Semiconductors.</li> </ul>					
	<ul> <li>Legal texts h</li> </ul>	ave been adapted to the new	company name whe	re appropriate.		
	<ul> <li>Table 1 "Prod</li> </ul>	duct overview": added				
<ul> <li><u>Section 1.2 "Features"</u>: updated</li> <li><u>Section 1.3 "Applications"</u>: amended</li> </ul>						
	Section 2 "Pinning information": amended					
	• Figure 1: sup	erseded by minimized packa	ge outline drawing			
	<ul> <li>Section 9 "Pa</li> </ul>	acking information": added				
	<ul> <li>Section 11 "L</li> </ul>	egal information": updated				
PUMX1_3	19990414	Preliminary specification	-	PUMX1_2		
PUMX1 2	19970709	Preliminary specification	-	PUMX1_1		

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### 11. Legal information

#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nexperia.com">http://www.nexperia.com</a>.

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PUMX1

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